



S E M I C O N D U C T O R

SR1020M2 THRU SR10200M2

SCHOTTKY BARRIER RECTIFIER
Reverse Voltage - 20 to 200 Volts
Forward Current - 10.0 Amperes

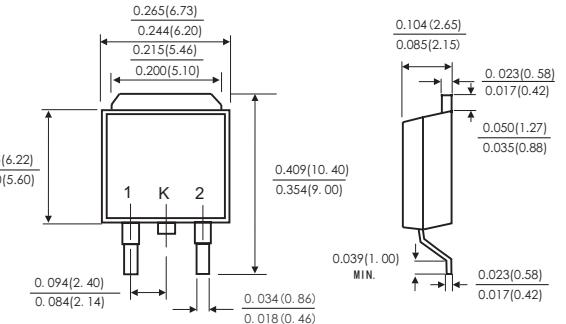
FEATURES

- Plastic package has Underwriters Laboratory Flammability Classification 94V-0
- Metal silicon junction, majority carrier conduction
- Guard ring for overvoltage protection
- Low power loss, high efficiency
- High current capability, Low forward voltage drop
- Single rectifier construction
- High surge capability
- For use in low voltage, high frequency inverters, free wheeling, and polarity protection applications
- High temperature soldering guaranteed: 260°C/10 seconds, 0.25"(6.35mm) from case
- Component in accordance to RoHS 2011/65/EU



TO-252

(DPAK)



Dimensions in inches and (millimeters)

MECHANICAL DATA

- Case: JEDEC TO-252 molded plastic body
- Terminals: Solderable per MIL-STD-202, method 208
- Polarity: As marked
- Mounting Position: Any

MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

(Ratings at 25°C ambient temperature unless otherwise specified, Single phase, half wave, resistive or inductive load. For capacitive load, derate by 20%.)

	Symbols	SR 1020M2	SR 1030M2	SR 1040M2	SR 1060M2	SR 10100M2	SR 10150M2	SR 10200M2	Units			
Maximum repetitive peak reverse voltage	V _{RRM}	20	30	40	60	100	150	200	Volts			
Maximum RMS voltage	V _{RMS}	14	21	28	42	70	105	140	Volts			
Maximum DC blocking voltage	V _{DC}	20	30	40	60	100	150	200	Volts			
Maximum average forward rectified current (see Fig.1)	I _(AV)	10.0						Amps				
Peak forward surge current 8.3ms single half sine-wave superimposed on rated load (JEDEC method)	I _{FSM}	150.0						Amps				
Maximum instantaneous forward voltage at 10.0 A (Note 1)	V _F	0.60		0.75	0.85	0.90	0.95	Volts				
Maximum instantaneous reverse current at rated DC blocking voltage (Note 1) T _A =25°C T _A =100°C T _A =125°C	I _R	200			50			μA				
		5			-			mA				
		-			5							
Typical thermal resistance (Note 2)	R _{θJC}	2.5						°C/W				
Operating junction temperature range	T _J	-55 to +150						°C				
Storage temperature range	T _{STG}	-55 to +150						°C				

Notes: 1. Pulse test: 300μs pulse width, 1% duty cycle

2. Thermal resistance from junction to case

RATINGS AND CHARACTERISTIC CURVES SR1020M2 THRU SR10200M2

FIG.1-FORWARD CURRENT DERATING CURVE

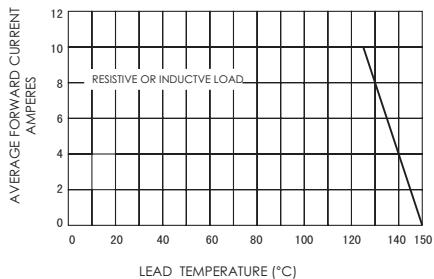


FIG.3-TYPICAL INSTANTANEOUS FORWARD CHARACTERISTICS

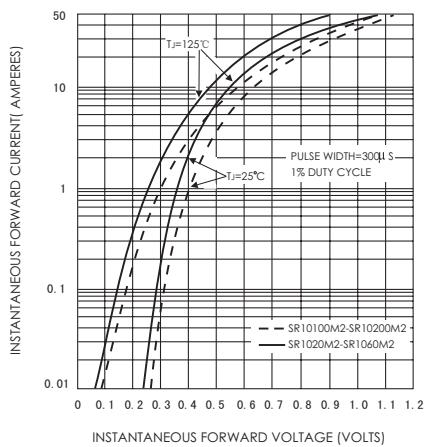


FIG.5-TYPICAL JUNCTION CAPACITANCE

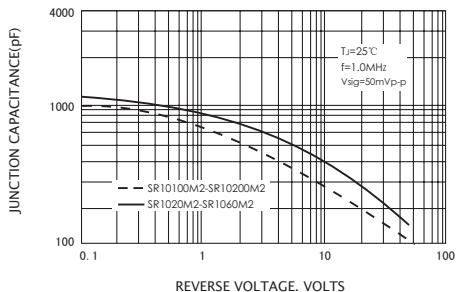


FIG.2-MAXIMUM NON-REPETITIVE PEAK FORWARD SURGE CURRENT

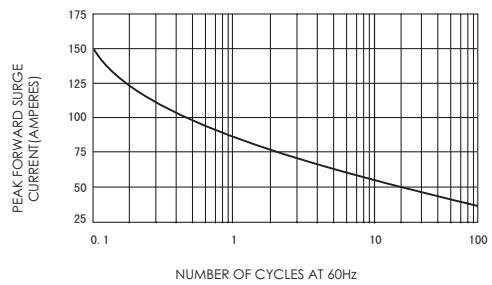


FIG.4-TYPICAL REVERSE CHARACTERISTICS

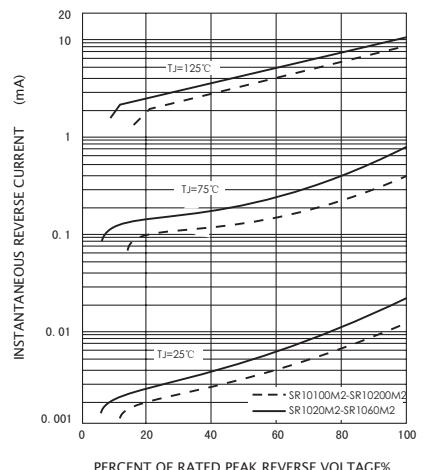


FIG.6-TYPICAL TRANSIENT THERMAL IMPEDANCE

